
2SC5246

Silicon NPN Epitaxial

HITACHI

ADE-208-264
1st. Edition

Application

VHF / UHF wide band amplifier

Features

- High gain bandwidth product
 $f_T = 12 \text{ GHz typ}$
- High gain, low noise figure
 $PG = 16.5 \text{ dB typ}$, $NF = 1.6 \text{ dB typ}$ at $f = 900 \text{ MHz}$

Outline

SMPAK



1. Emitter
2. Base
3. Collector

Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Item	Symbol	Ratings	Unit
Collector to base voltage	V_{CBO}	15	V
Collector to emitter voltage	V_{CEO}	8	V
Emitter to base voltage	V_{EBO}	1.5	V
Collector current	I_{C}	20	mA
Collector power dissipation	P_{C}	80	mW
Junction temperature	T_{j}	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

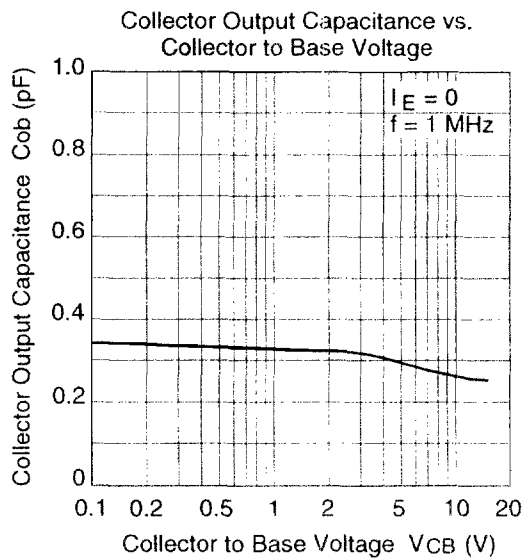
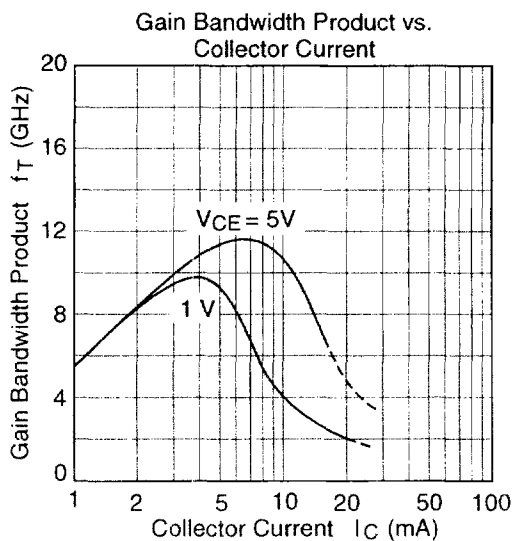
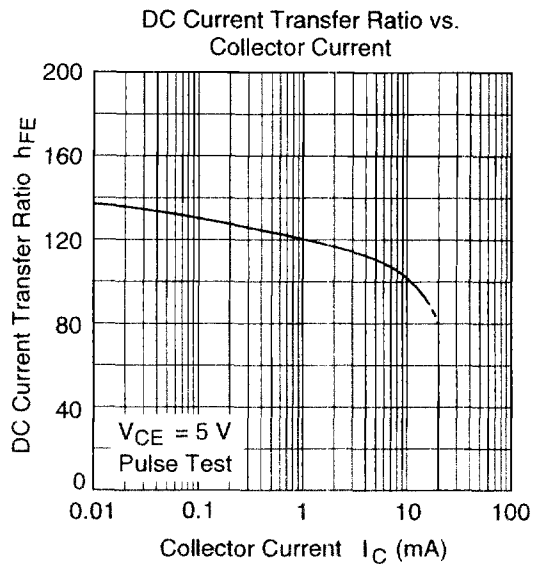
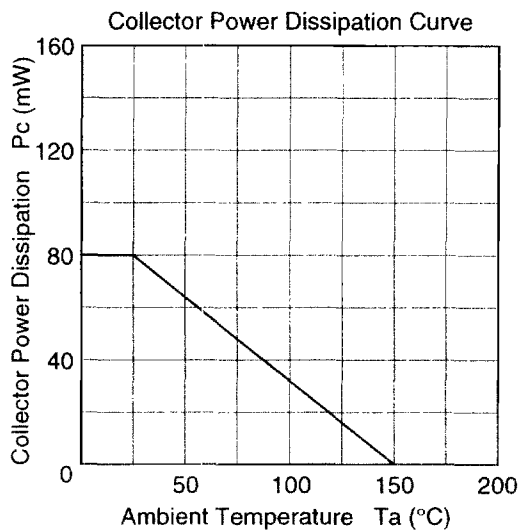
Note: Marking is "ZC—".

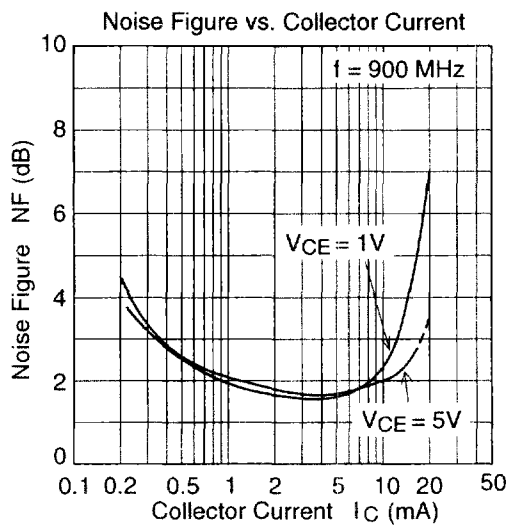
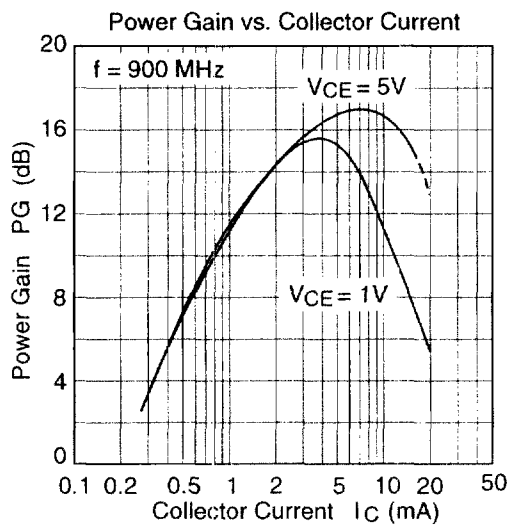
Attention: This device is very sensitive to electro static discharge.

It is recommended to adopt appropriate cautions when handling this transistor.

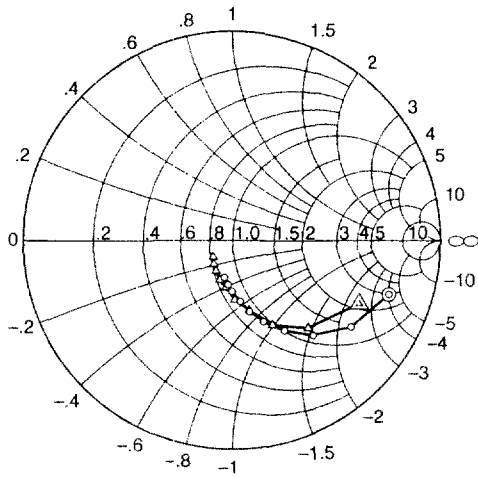
Electrical Characteristics ($T_a = 25^\circ\text{C}$)

Item	Symbol	Min	Typ	Max	Unit	Test conditions
Collector cutoff current	I_{CBO}	—	—	10	μA	$V_{\text{CB}} = 15\text{ V}, I_{\text{E}} = 0$
	I_{CEO}	—	—	1	mA	$V_{\text{CE}} = 8\text{ V}, R_{\text{BE}} = \infty$
Emitter cutoff current	I_{EBO}	—	—	10	μA	$V_{\text{EB}} = 1.5\text{ V}, I_{\text{C}} = 0$
DC current transfer ratio	h_{FE}	50	100	160		$V_{\text{CE}} = 5\text{ V}, I_{\text{C}} = 10\text{ mA}$
Collector output capacitance	C_{ob}	—	0.3	0.8	pF	$V_{\text{CB}} = 5\text{ V}, I_{\text{E}} = 0,$ $f = 1\text{ MHz}$
Gain bandwidth product	f_{T}	9	12	—	GHz	$V_{\text{CE}} = 5\text{ V}, I_{\text{C}} = 5\text{ mA}$
Power gain	PG	14	16.5	—	dB	$V_{\text{CE}} = 5\text{ V}, I_{\text{C}} = 10\text{ mA},$ $f = 900\text{ MHz}$
Noise figure	NF	—	1.6	2.5	dB	$V_{\text{CE}} = 5\text{ V}, I_{\text{C}} = 5\text{ mA},$ $f = 900\text{ MHz}$





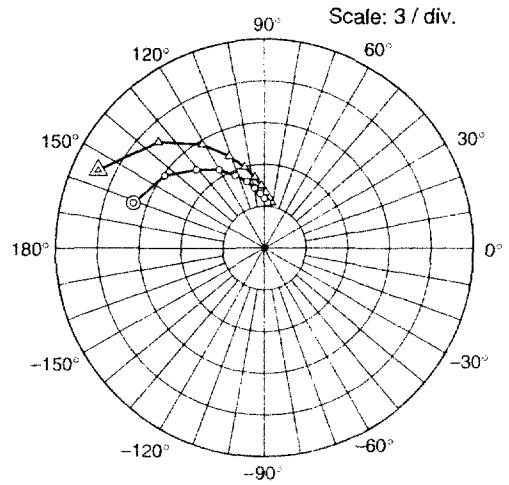
S11 Parameter vs. Frequency



Condition: $V_{CE} = 5\text{ V}$, $Z_o = 50\ \Omega$
200 to 2000 MHz (200 MHz step)

○ — (IC = 5 mA)
△ — (IC = 10 mA)

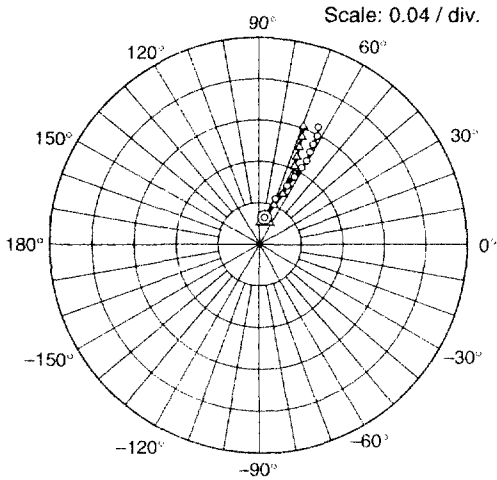
S21 Parameter vs. Frequency



Condition: $V_{CE} = 5\text{ V}$, $Z_o = 50\ \Omega$
200 to 2000 MHz (200 MHz step)

○ — (IC = 5 mA)
△ — (IC = 10 mA)

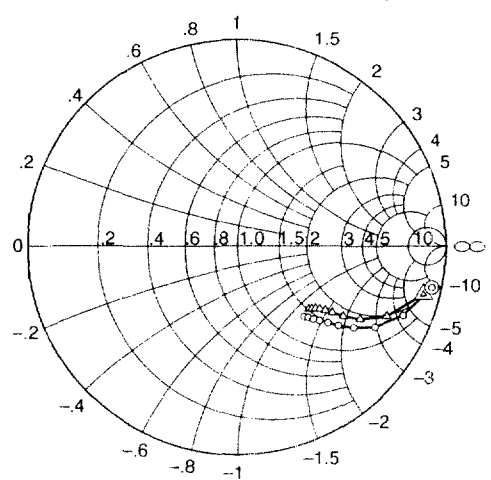
S12 Parameter vs. Frequency



Condition: $V_{CE} = 5\text{ V}$, $Z_o = 50\ \Omega$
200 to 2000 MHz (200 MHz step)

○ — (IC = 5 mA)
△ — (IC = 10 mA)

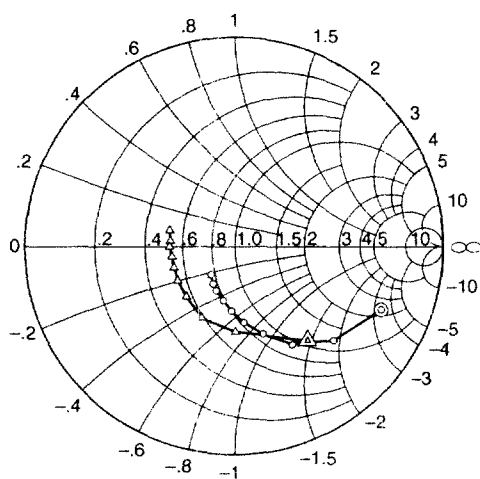
S22 Parameter vs. Frequency



Condition: $V_{CE} = 5\text{ V}$, $Z_o = 50\ \Omega$
200 to 2000 MHz (200 MHz step)

○ — (IC = 5 mA)
△ — (IC = 10 mA)

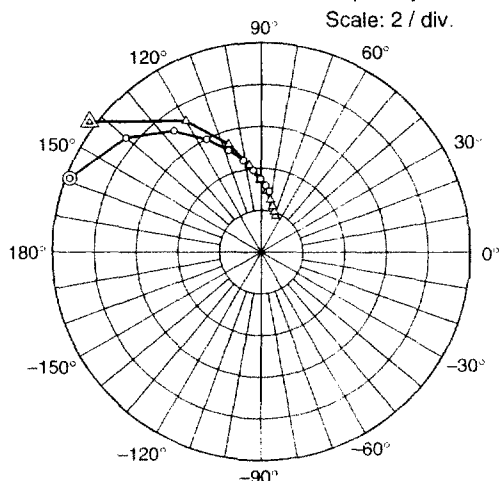
S11 Parameter vs. Frequency



Condition: $V_{CE} = 1\text{ V}$, $Z_o = 50\ \Omega$
200 to 2000 MHz (200 MHz step)

○ — ○ ($I_C = 5\text{ mA}$)
△ — △ ($I_C = 10\text{ mA}$)

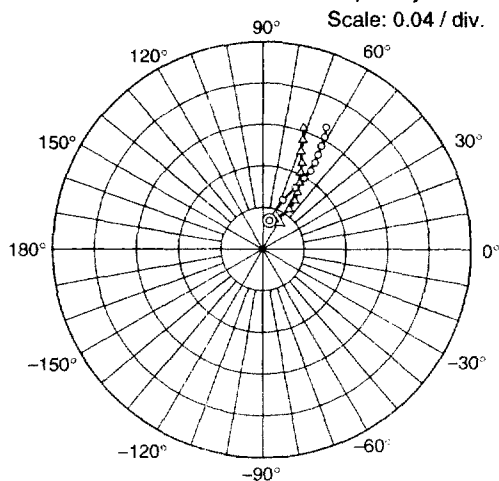
S21 Parameter vs. Frequency



Condition: $V_{CE} = 1\text{ V}$, $Z_o = 50\ \Omega$
200 to 2000 MHz (200 MHz step)

○ — ○ ($I_C = 5\text{ mA}$)
△ — △ ($I_C = 10\text{ mA}$)

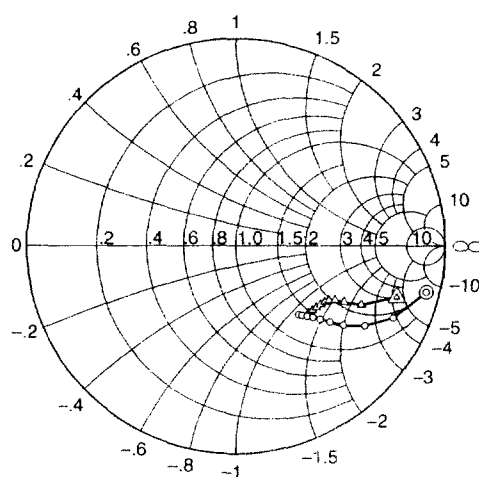
S12 Parameter vs. Frequency



Condition: $V_{CE} = 1\text{ V}$, $Z_o = 50\ \Omega$
200 to 2000 MHz (200 MHz step)

○ — ○ ($I_C = 5\text{ mA}$)
△ — △ ($I_C = 10\text{ mA}$)

S22 Parameter vs. Frequency



Condition: $V_{CE} = 1\text{ V}$, $Z_o = 50\ \Omega$
200 to 2000 MHz (200 MHz step)

○ — ○ ($I_C = 5\text{ mA}$)
△ — △ ($I_C = 10\text{ mA}$)

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S Parameter ($V_{CE} = 5\text{ V}$, $I_C = 5\text{ mA}$, $Z_0 = 50\ \Omega$)

Freq. (MHz)	S11		S21		S12		S22	
	MAG.	ANG.	MAG.	ANG.	MAG.	ANG.	MAG.	ANG.
200	0.793	-18.9	9.98	161	0.026	78.6	0.955	-12.0
400	0.702	-36.0	8.88	144	0.047	70.2	0.864	-22.7
600	0.594	-49.4	7.63	131	0.063	64.6	0.768	-30.3
800	0.495	-59.9	6.54	120	0.074	62.4	0.684	-34.8
1000	0.415	-69.1	5.65	112	0.085	61.1	0.620	-38.0
1200	0.349	-76.8	4.94	105	0.093	60.5	0.572	-40.1
1400	0.293	-83.0	4.37	99.4	0.102	61.3	0.535	-42.0
1600	0.241	-90.2	3.93	94.7	0.110	61.7	0.508	-43.7
1800	0.214	-93.9	3.57	90.2	0.119	61.9	0.486	-45.0
2000	0.181	-103	3.28	89.3	0.127	63.4	0.469	-46.4

S Parameter ($V_{CE} = 5\text{ V}$, $I_C = 10\text{ mA}$, $Z_0 = 50\ \Omega$)

Freq. (MHz)	S11		S21		S12		S22	
	MAG.	ANG.	MAG.	ANG.	MAG.	ANG.	MAG.	ANG.
200	0.679	-26.4	13.2	155	0.024	76.2	0.924	-14.6
400	0.552	-48.9	10.8	135	0.041	69.0	0.794	-25.1
600	0.445	-64.5	8.71	121	0.054	64.8	0.687	-30.6
800	0.342	-76.7	7.12	111	0.064	64.5	0.611	-33.3
1000	0.283	-88.1	5.99	104	0.073	64.5	0.559	-34.9
1200	0.228	-98.3	5.15	97.8	0.083	65.7	0.526	-36.0
1400	0.191	-105	4.50	93.0	0.092	66.8	0.501	-37.3
1600	0.166	-119	4.01	88.6	0.102	67.9	0.483	-38.5
1800	0.136	-124	3.62	84.6	0.112	68.3	0.470	-40.1
2000	0.123	-140	3.31	81.1	0.122	69.5	0.460	-41.3

S Parameter ($V_{CE} = 1\text{ V}$, $I_C = 5\text{ mA}$, $Z_0 = 50\ \Omega$)

Freq. (MHz)	S11		S21		S12		S22	
	MAG.	ANG.	MAG.	ANG.	MAG.	ANG.	MAG.	ANG.
200	0.764	-23.4	9.82	159	0.028	77.1	0.938	-13.7
400	0.651	-43.6	8.47	140	0.051	67.8	0.830	-24.8
600	0.545	-59.5	7.13	126	0.067	62.1	0.727	-31.9
800	0.439	-72.2	5.98	116	0.079	59.7	0.641	-36.7
1000	0.366	-83.3	5.10	108	0.088	58.7	0.581	-39.2
1200	0.308	-92.9	4.46	101	0.097	59.0	0.537	-41.3
1400	0.263	-102	3.92	95.3	0.105	59.7	0.505	-43.1
1600	0.228	-113	3.51	90.4	0.114	60.4	0.481	-44.8
1800	0.205	-120	3.19	86.0	0.123	61.1	0.461	-46.5
2000	0.175	-131	2.92	82.3	0.132	62.5	0.447	-47.8

S Parameter ($V_{CE} = 1\text{ V}$, $I_C = 10\text{ mA}$, $Z_0 = 50\ \Omega$)

Freq. (MHz)	S11		S21		S12		S22	
	MAG.	ANG.	MAG.	ANG.	MAG.	ANG.	MAG.	ANG.
200	0.570	-52.3	10.3	143	0.030	66.1	0.811	-17.9
400	0.443	-89.8	7.23	120	0.046	56.8	0.665	-25.2
600	0.376	-115	5.37	107	0.056	56.7	0.586	-27.6
800	0.333	-134	4.20	97.7	0.064	58.4	0.534	-29.0
1000	0.317	-149	3.43	91.0	0.073	60.8	0.519	-30.6
1200	0.309	-161	2.93	85.0	0.082	63.8	0.505	-32.5
1400	0.305	-171	2.53	80.1	0.091	65.8	0.495	-34.8
1600	0.312	-180	2.25	76.1	0.101	68.1	0.487	-37.6
1800	0.309	175	2.03	72.0	0.112	69.9	0.481	-40.3
2000	0.320	166	1.84	68.6	0.123	71.4	0.476	-43.1